

METHOD OF MAKING A VERTICAL COMPOUND
SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE
Atty Dkt. No. ONS00505 SHEET 1 OF 4

ONS00505 HADIZAD

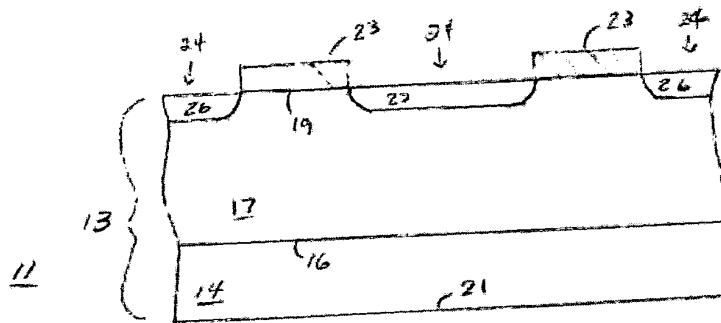


FIG. 1

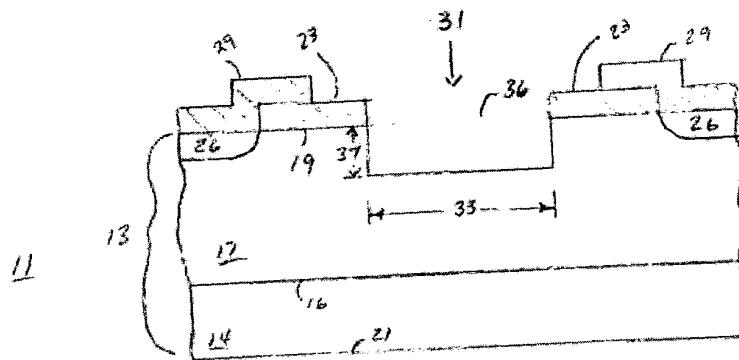


FIG. 2

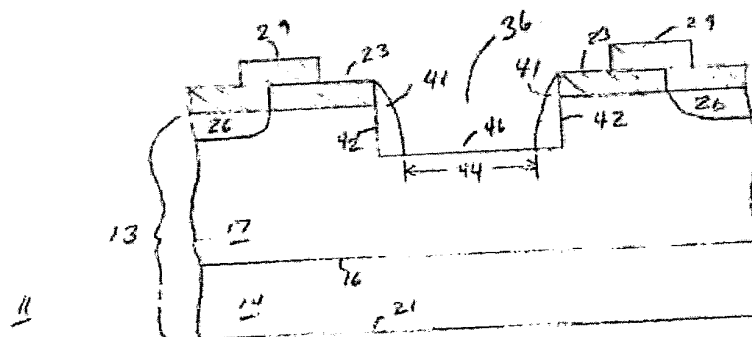


FIG. 3

METHOD OF MAKING A VERTICAL COMPOUND
SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE
Atty Dkt. No. ONS00505 SHEET 2 OF 4

ONS00505 HADIZAD

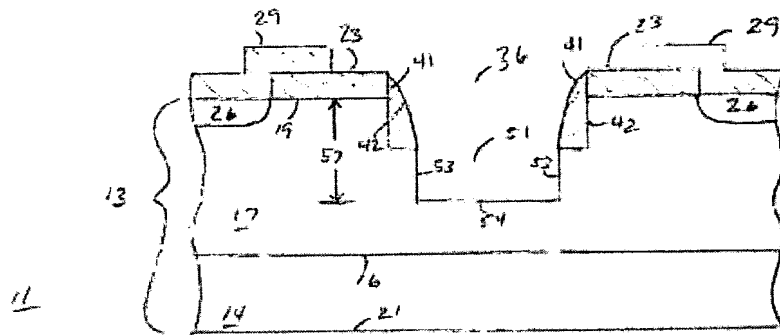


FIG. 4

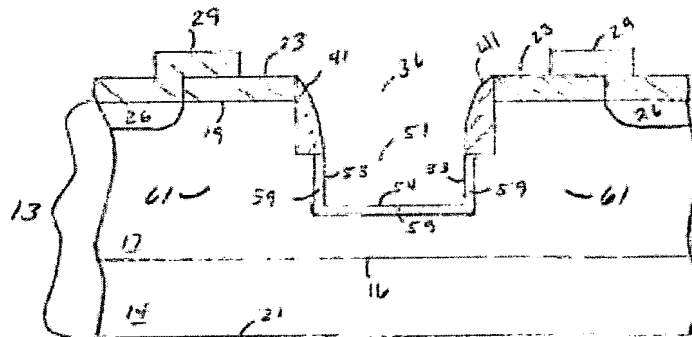
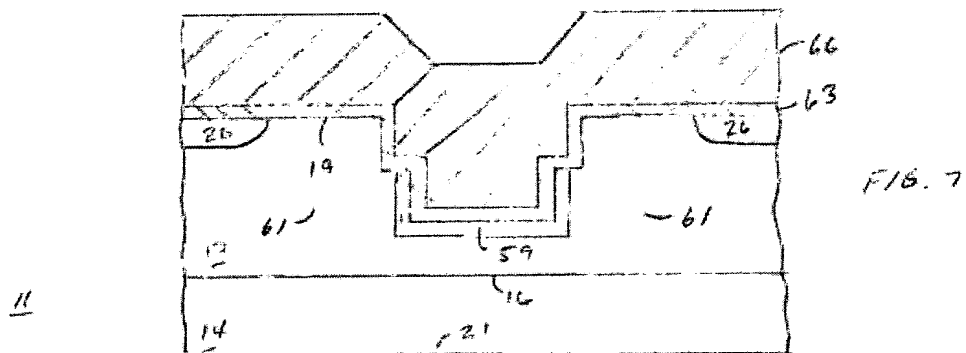
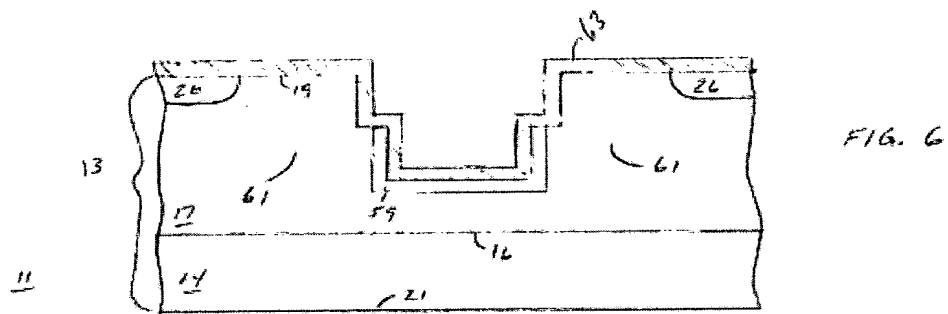


FIG. 5

METHOD OF MAKING A VERTICAL COMPOUND
SEMICONDUCTOR FIELD EFFECT TRANSISTOR DEVICE
Atty Dkt. No. ONS00505 SHEET 3 OF 4

ONS00505 HADIZAD



Atty Dkt. No. ONS00505 SHEET 4 OF 4

DN500505 HADIZAD

